

# **General Description**

The WSF15P10 is the highest performance trench P-ch MOSFET with extreme high cell density , which provide excellent RDSON and gate charge for most of the synchronous buck converter applications .

The WSF15P10 meet the RoHS and Green Product requirement,100% EAS guaranteed with full function reliability approved.

### **Features**

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% FAS Guaranteed
- Green Device Available

# **Product Summery**

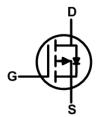
BVDSS	RDSON	ID
-100V	150mΩ	-13A

# **Applications**

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

## **TO-252 Pin Configuration**





### **Absolute Maximum Ratings**

Symbol	Parameter Rating		Units	
$V_{DS}$	Drain-Source Voltage	-100	V	
$V_{GS}$	Gate-Source Voltage	V		
I <sub>D</sub> @T <sub>C</sub> =25℃	Continuous Drain Current, -V <sub>GS</sub> @ -10V <sup>1</sup> -13			
I <sub>D</sub> @T <sub>C</sub> =100°C	Continuous Drain Current, -V <sub>GS</sub> @ -10V <sup>1</sup>	А		
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup> -45		А	
EAS	Single Pulse Avalanche Energy <sup>3</sup>	25	mJ	
I <sub>AS</sub>	Avalanche Current	-10	Α	
P <b></b> _@T <sub>C</sub> =25°C	Total Power Dissipation <sup>4</sup> 50		W	
T <sub>STG</sub>	Storage Temperature Range -55 to 150		$^{\circ}$	
TJ	Operating Junction Temperature Range -55 to 150		$^{\circ}$	

### **Thermal Data**

Symbol	Parameter	Тур.	Max.	Unit
$R_{ heta JA}$	Thermal Resistance Junction-Ambient <sup>1</sup>		50	°C/W
$R_{ heta JC}$	Thermal Resistance Junction-Case <sup>1</sup>		2.5	°C/W



# Electrical Characteristics (T<sub>J</sub>=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>D</sub> =-250uA	-100			V
$\triangle BV_{DSS}/\triangle T_{J}$	BV <sub>DSS</sub> Temperature Coefficient	Reference to 25℃, I <sub>D</sub> =-1mA		-0.021		V/°C
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =-10V , I <sub>D</sub> =-5.5A		150	190	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =-250uA	-2	-3	-4	V
$ riangle V_{GS(th)}$	V <sub>GS(th)</sub> Temperature Coefficient	VGS-VDS , ID230UA		4.08		mV/℃
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =-48V , V <sub>GS</sub> =0V , T <sub>J</sub> =25°C V <sub>DS</sub> =-48V , V <sub>GS</sub> =0V , T <sub>J</sub> =55°C			1	- uA
IDSS	Diam-Source Leakage Current				5	
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = $\pm 20V$ , $V_{DS}$ = $0V$			±100	nA
gfs	Forward Transconductance	V <sub>DS</sub> =-10V , I <sub>D</sub> =-6A		8		S
Qg	Total Gate Charge (-4.5V)	V <sub>DS</sub> =-50V , V <sub>GS</sub> =-10V , I <sub>D</sub> =-5.5A		13.7		
$Q_gs$	Gate-Source Charge			3		nC
$Q_{gd}$	Gate-Drain Charge			3.8		
T <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD}$ =-30V , $V_{GS}$ =-10V , $R_{G}$ =6 $\Omega$ , $I_{D}$ =-1A ,RG=30 $\Omega$ .		8		
Tr	Rise Time			4		ns
T <sub>d(off)</sub>	Turn-Off Delay Time			22		115
T <sub>f</sub>	Fall Time			12		
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =-30V , V <sub>GS</sub> =0V , f=1MHz		600		
C <sub>oss</sub>	Output Capacitance			60		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			34		

# **Guaranteed Avalanche Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
EAS	Single Pulse Avalanche Energy <sup>5</sup>	V <sub>DD</sub> =-25V , L=0.5mH , I <sub>AS</sub> =-10A	20			mJ

## **Diode Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I <sub>S</sub>	Continuous Source Current <sup>1,6</sup>	-V <sub>G</sub> =V <sub>D</sub> =0V , Force Current			-2.0	Α
I <sub>SM</sub>	Pulsed Source Current <sup>2,6</sup>				-45	Α
$V_{SD}$	Diode Forward Voltage <sup>2</sup>	V <sub>GS</sub> =0V , I <sub>S</sub> =-1A , T <sub>J</sub> =25℃			-1.2	V

#### Note

- 1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper, t≤10sec.
- 2.The data tested by pulsed , pulse width  $\leq$  300us , duty cycle  $\leq$  2%
- 3.The EAS data shows Max. rating . The test condition is  $V_{DD}$ =-25V, $V_{GS}$ =-10V,L=0.5mH, $I_{AS}$ =-10A
- 4.The power dissipation is limited by 150 ℃ junction temperature
- 5.The Min. value is 100% EAS tested guarantee.
- 6. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.



# **Typical Characteristics**

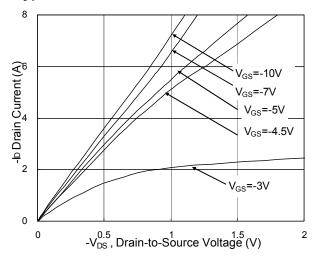


Fig.1 Typical Output Characteristics

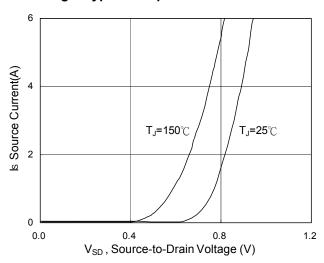


Fig.3 Forward Characteristics Of Reverse

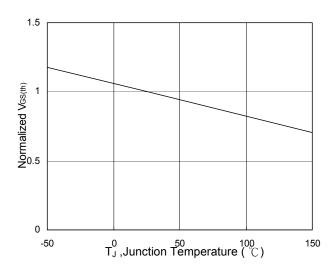


Fig.5 Normalized  $V_{GS(th)}$  v.s  $T_J$ 

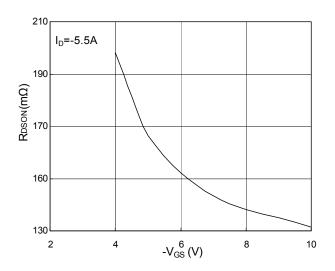


Fig.2 On-Resistance v.s Gate-Source

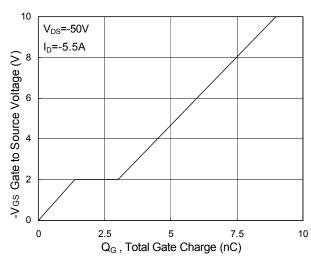


Fig.4 Gate-Charge Characteristics

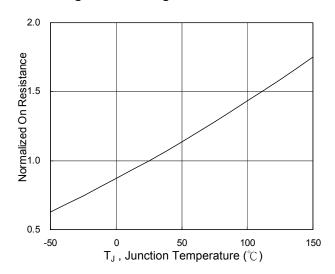
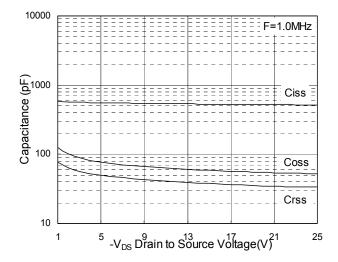


Fig.6 Normalized R<sub>DSON</sub> v.s T<sub>J</sub>







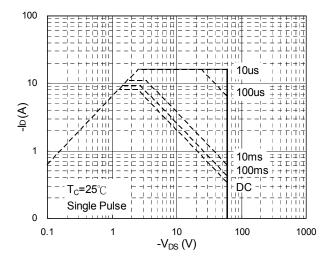


Fig.7 Capacitance

Fig.8 Safe Operating Area

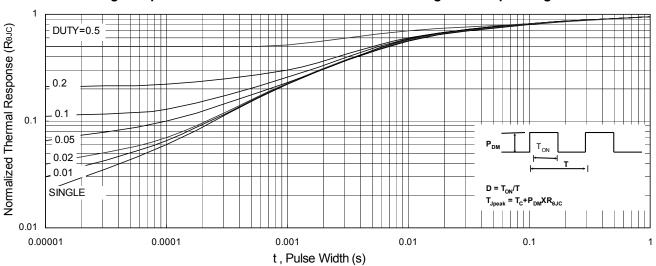


Fig.9 Normalized Maximum Transient Thermal Impedance

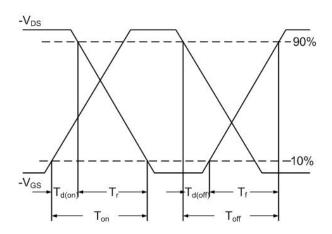


Fig.10 Switching Time Waveform

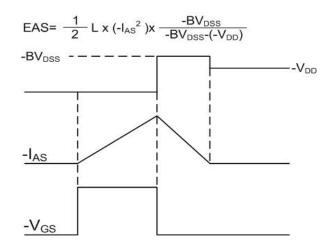


Fig.11 Unclamped Inductive Waveform



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